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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/815,653	04/02/2004	Shunpei Yamazaki	0756-7280	9676
31780 ERIC ROBINS	7590 11/29/2007 ON	EXAMINER		
PMB 955		SEFER, AHMED N		
21010 SOUTHBANK ST. POTOMAC FALLS, VA 20165			ART UNIT	PAPER NUMBER
101011110111111111111111111111111111111			2826	
			MAIL DATE	DELIVERY MODE
	•		11/29/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

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•	,	Application No.	Applicant(s)		
Office Action Summary		10/815,653	YAMAZAKI ET AL.		
		Examiner	Art Unit		
		A. Sefer	2826		
Period fo	The MAILING DATE of this communication apport Reply	ears on the cover sheet with the o	orrespondence address		
WHIC - Exte after - If NC - Failu Any	IORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DAINS of time may be available under the provisions of 37 CFR 1.13 or SIX (6) MONTHS from the mailing date of this communication. Diperiod for reply is specified above, the maximum statutory period we are to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing led patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tir will apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).		
Status					
	Responsive to communication(s) filed on 05 Se		•		
	This action is FINAL . 2b) This action is non-final.				
3)□	Since this application is in condition for allowar	•			
	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.		
Disposit	ion of Claims				
4)⊠	Claim(s) 39,40,43,44,47,48,51,52,55,56,59-61	and 66-69 is/are pending in the	application.		
	4a) Of the above claim(s) is/are withdraw	vn from consideration.	•		
	Claim(s) is/are allowed.				
	Claim(s) <u>39,40,43,44,47,48,51,52,55,56,59-61</u>	and 66-69 is/are rejected.			
	Claim(s) is/are objected to.				
8)	Claim(s) are subject to restriction and/or	r election requirement.			
Applicat	ion Papers				
9)[The specification is objected to by the Examiner	r.			
-	The drawing(s) filed on is/are: a) acce		Examiner.		
	Applicant may not request that any objection to the				
	Replacement drawing sheet(s) including the correcti	ion is required if the drawing(s) is ob	jected to. See 37 CFR 1.121(d).		
11)	The oath or declaration is objected to by the Ex-	aminer. Note the attached Office	Action or form PTO-152.		
Priority (under 35 U.S.C. § 119				
12)	Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a))-(d) or (f)		
	☐ All b)☐ Some * c)☐ None of:	p	(4) 4. (1).		
	1. ☐ Certified copies of the priority documents have been received.				
	2. Certified copies of the priority documents have been received in Application No				
	3. Copies of the certified copies of the prior	ity documents have been receive	ed in this National Stage		
	application from the International Bureau	(PCT Rule 17.2(a)).			
* 9	See the attached detailed Office action for a list of	of the certified copies not receive	ed.		
Attachmen	• •				
	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary			
	mation Disclosure Statement(s) (PTO/SB/08)	Paper No(s)/Mail Da 5) Notice of Informal P			
	er No(s)/Mail Date <u>10/2/07</u> .	6)			

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DETAILED ACTION

Response to Amendment

1. The amendment filed September 5, 2007 has been entered and claims 41, 42, 45, 46, 49, 50, 53, 54, 57 and 58 have been cancelled.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 39, 43, 60, 61 and 66-68 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wakai et al. ("Wakai") USPN 5,229,644 in view of Tomoike et al. ("Tomoike") JP 6-118440.

Wakai discloses in figs. 3-13 a display device comprising: a pair of substrates 101/116 facing each other; a thin film transistor 111 comprising a coplanar thin film transistor (as in claim 66) or an inverted-staggered thin film transistor (as in claim 67) formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 104 comprising amorphous silicon (as in claim 43); a layer 108 comprising a resinous material comprising acrylic resin (as in claim 60) or methyl esters of acrylic acid (as in claim 61) (col. 4, line 65) covering the thin film transistor; and a pixel electrode 110 formed over the layer, and electrically connected to the thin film transistor, wherein a resinous layer (the lower/upper portion of region 108) being provided on a surface of one of the pair of the substrates (as in claims 39 and 43),

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but does not specifically disclose resinous substrates facing each other and each having an uneven surface.

Tomoike in figs. 1 and 3 a display device comprising: a pair of resinous substrates 1/12 comprising PES (paragraphs 25 and 31 of machine translated document) which at least one selected from the group consisting of PEN, PES and polymide (as in claim 68) facing each other and each having an uneven surface; a thin film transistor 2 formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 6.

Note the recitation, "wherein the resinous layer palanarizes the uneven surface" constitutes a function language. In re Casey, 152 USPQ 235 (CCPA 1967); see also In re Otto, 136 USPQ 458, 459 (CCPA 1963).

Therefore, in view of Tomoike's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Wakai's device by incorporating resinous substrates. The motivation would be to provide substrates with a low cost and readily available material. Therefore, it would have been obvious to combine Wakai and Tomoike so as to yield the device of claims 39 and 43.

4. Claims 40, 44, 60, 61, 66, 67 and 69, as understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Wakai in view of Tomoike.

Wakai discloses in figs. 3-13 a display device comprising: a pair of substrates 101/116 facing each other; a thin film transistor 111 comprising a coplanar thin film transistor (as in claim 66) or an inverted-staggered thin film transistor (as in claim 67), wherein the thin film transistor has a channel formation region 104 comprising amorphous silicon (as in claim 44) formed over one of the pair substrates; a layer 108 comprising a resinous material covering the

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thin film transistor; and a pixel electrode 110 formed over the layer, and electrically connected to the thin film transistor, wherein a resinous layer (the lower/upper portion of region 108) comprising acrylic resin (as in claim 60) or methyl esters of acrylic acid (as in claim 61) (col. 4, line 65) being provided on a surface of one of the pair of substrates (as in claims 40 and 44), but

Tomoike in figs. 1 and 3 a display device comprising: a pair of flexible (paragraphs 25 and 31 of machine translated document) substrates 1/12 comprising PES which at least one selected from the group consisting of PEN, PES and polymide (as in claim 69) facing each other and each having an uneven surface; a thin film transistor 2 formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 6.

does not specifically disclose flexible substrate having an uneven surface.

Note the recitation, "wherein the resinous layer palanarizes the uneven surface" constitutes a function language. In re Casey, 152 USPQ 235 (CCPA 1967); see also In re Otto, 136 USPQ 458, 459 (CCPA 1963).

Therefore, in view of Tomoike's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Wakai's device by incorporating flexible substrates. The motivation would be to provide substrates with a low cost and readily available material. Therefore, it would have been obvious to combine Wakai and Tomoike so as to yield the device of claims 40 and 44.

5. Claims 47, 51, 55, 59-61, 66-68, as understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Wakai in view of Mori JP 3-13273 and Tomoike.

Wakai discloses in figs. 3-13 a display device comprising: a pair of resinous substrates 101/116 facing each other an uneven surface; a thin film transistor 111 comprising a coplanar

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thin film transistor (as in claim 66) or an inverted-staggered thin film transistor (as in claim 67) formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 104; a layer 108 comprising a resinous material comprising acrylic resin (as in claim 60) or methyl esters of acrylic acid (as in claim 61) (col. 4, line 65) covering the thin film transistor; and a pixel electrode 110 formed over the layer, and electrically connected to the thin film transistor, wherein a resinous layer (the lower/upper portion of region 108) is provided on a surface of one of the pair of filmy substrates, but discloses neither microcrystalline silicon nor resinous substrate having an uneven surface.

Mori discloses a display device comprising a thin film transistor, wherein the thin film transistor has a channel formation material comprising microcrystalline silicon.

Tomoike discloses in figs. 1 and 3 a display device comprising: a pair of resinous substrates 1/12 comprising PES (paragraphs 25 and 31 of machine translated document) which at least one selected from the group consisting of PEN, PES and polymide (as in claim 68) facing each other and each having an uneven surface; a thin film transistor 2 formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 6.

Note the recitation, "wherein the resinous layer palanarizes the uneven surface" constitutes a function language. In re Casey, 152 USPQ 235 (CCPA 1967); see also In re Otto, 136 USPQ 458, 459 (CCPA 1963).

Therefore, in view of Tomoike's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Wakai's device by incorporating resinous substrates. The motivation would be to provide substrates with a low cost and readily available material. Therefore, it would have been obvious to combine Wakai and Tomoike so as

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to yield the device of claims 47, 51 and 55. It would have been obvious to employ microcrystalline silicon to achieve a high-speed switching as taught by Mori.

Re claim 59, the limitation fails to further limit the display device structure but only limits the method of making the channel.

6. Claims 48, 52, 56, 59-61, 66, 67 and 69, as understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Wakai in view of Mori and Tomoike.

Wakai discloses in figs. 3-13 a display device comprising: a pair of substrates 101/116 facing each other; a thin film transistor 111 comprising a coplanar thin film transistor (as in claim 66) or an inverted-staggered thin film transistor (as in claim 67), wherein the thin film transistor has a channel formation region 104 comprising amorphous silicon formed over one of the pair substrates; a layer 108 covering the thin film transistor; and a pixel electrode 110 formed over the layer or silicon oxide (as in claims 50, 54 and 58), and electrically connected to the thin film transistor, wherein a resinous layer (the lower/upper portion of region 108) comprising acrylic resin (as in claim 60) or methyl esters of acrylic acid (as in claim 61) (col. 4, line 65) being provided on a surface of one of the pair of substrates (as in claims 40, 42, 44 and 46), but discloses neither microcrystalline silicon nor flexible substrate having an uneven surface

Mori discloses a display device comprising a thin film transistor, wherein the thin film transistor has a channel formation material comprising microcrystalline silicon

Tomoike discloses in figs. 1 and 3 a display device comprising: a pair of resinous substrates 1/12 comprising PES (paragraphs 25 and 31 of machine translated document) which at least one selected from the group consisting of PEN, PES and polymide (as in claim 68) facing

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each other and each having an uneven surface; a thin film transistor 2 formed over one of the pair of substrates, wherein the thin film transistor has a channel formation region 6.

Note the recitation, "wherein the resinous layer palanarizes the uneven surface" constitutes a function language. In re Casey, 152 USPQ 235 (CCPA 1967); see also In re Otto, 136 USPQ 458, 459 (CCPA 1963).

Therefore, in view of Tomoike's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Wakai's device by incorporating resinous substrates. The motivation would be to provide substrates with a low cost and readily available material. Therefore, it would have been obvious to combine Wakai and Tomoike so as to yield the device of claims 48, 52 and 56. It would have been obvious to employ microcrystalline silicon to achieve a high-speed switching as taught by Mori.

Re claim 59, the limitation fails to further limit the display device structure but only limits the method of making the channel.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period

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will expire on the date the advisory action is mailed, and any extension fee pursuant to 37

CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

however, will the statutory period for reply expire later than SIX MONTHS from the date of this

final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to A. Sefer whose telephone number is (571) 272-1921.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Sue Purvis can be reached on (571) 272-1236.

Information regarding the status of an application may be obtained from the Patent

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ANS

November 23, 2007

/A. Sefer/ Primary Examiner

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